



# Commissioning of a Two-Photon Absorption laser setup

Two-Photon Absorption Transient-Current Technique

Carmel Neuburger<sup>1</sup>

Supervisors: Marcos Fernandez<sup>2</sup>, Michael Moll<sup>1</sup>

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CERN EP-DT summer students DT  
seminar 20, August 2019



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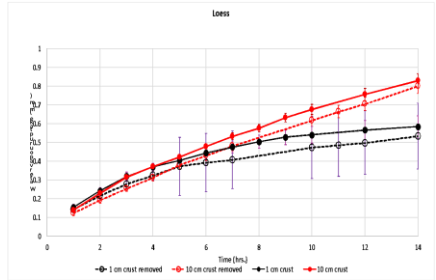
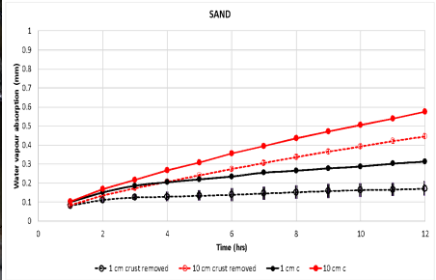
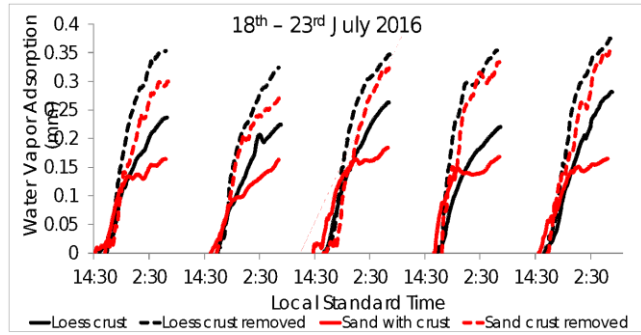
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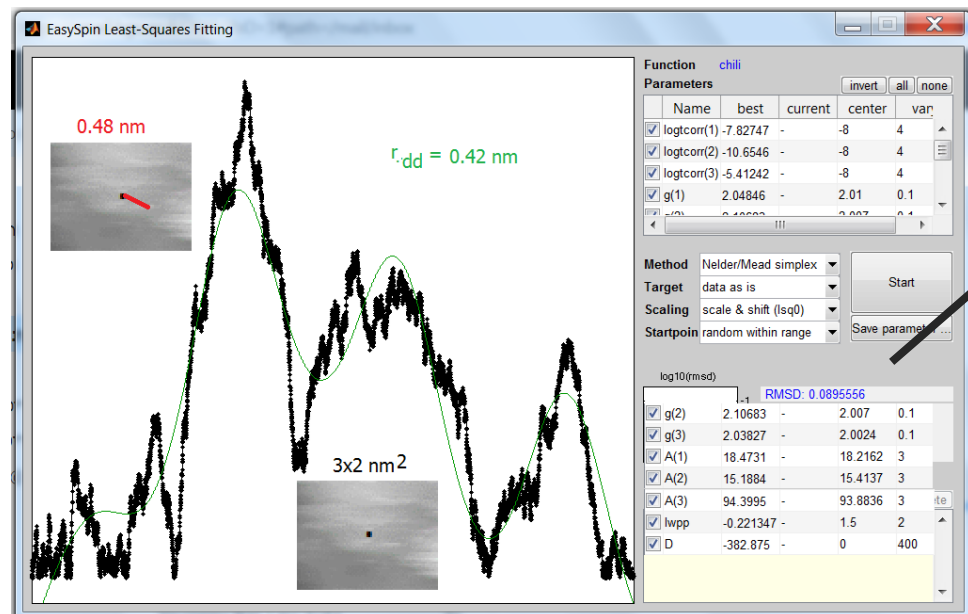
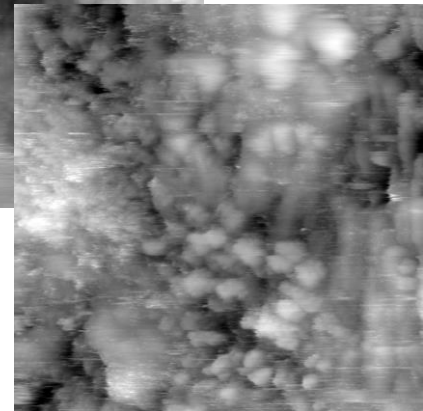
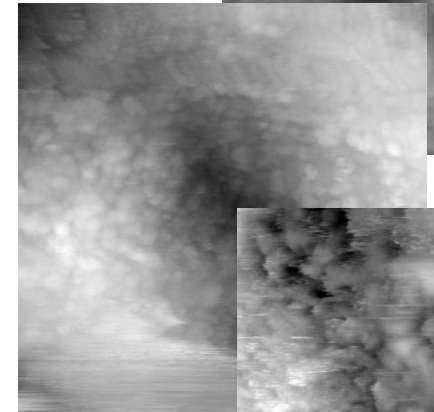
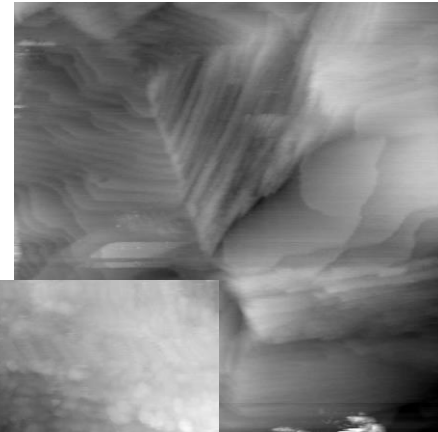
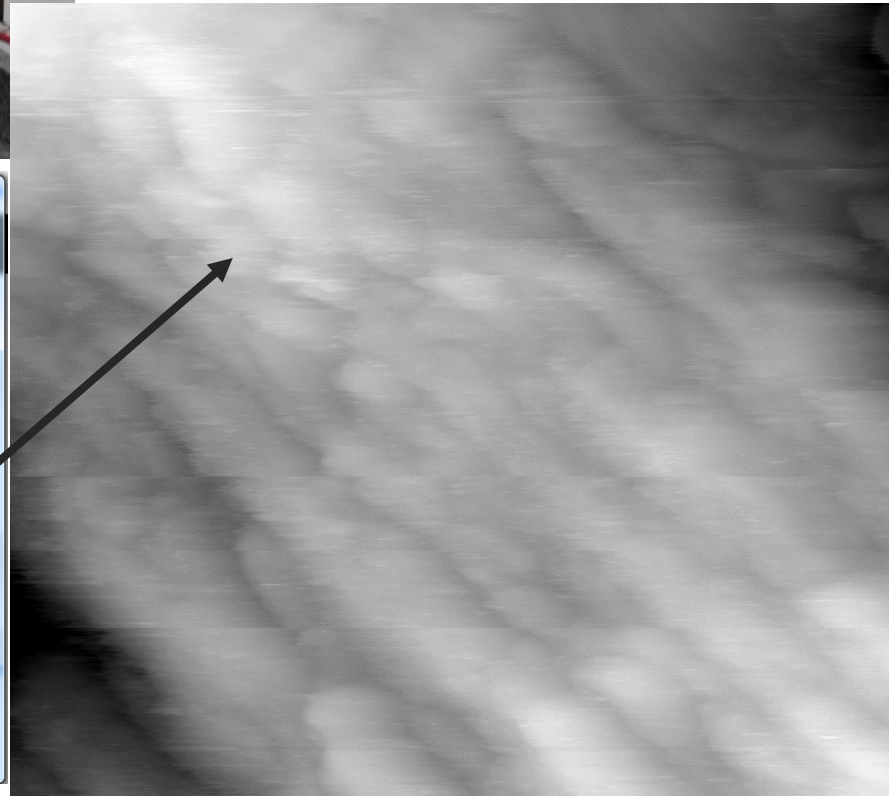
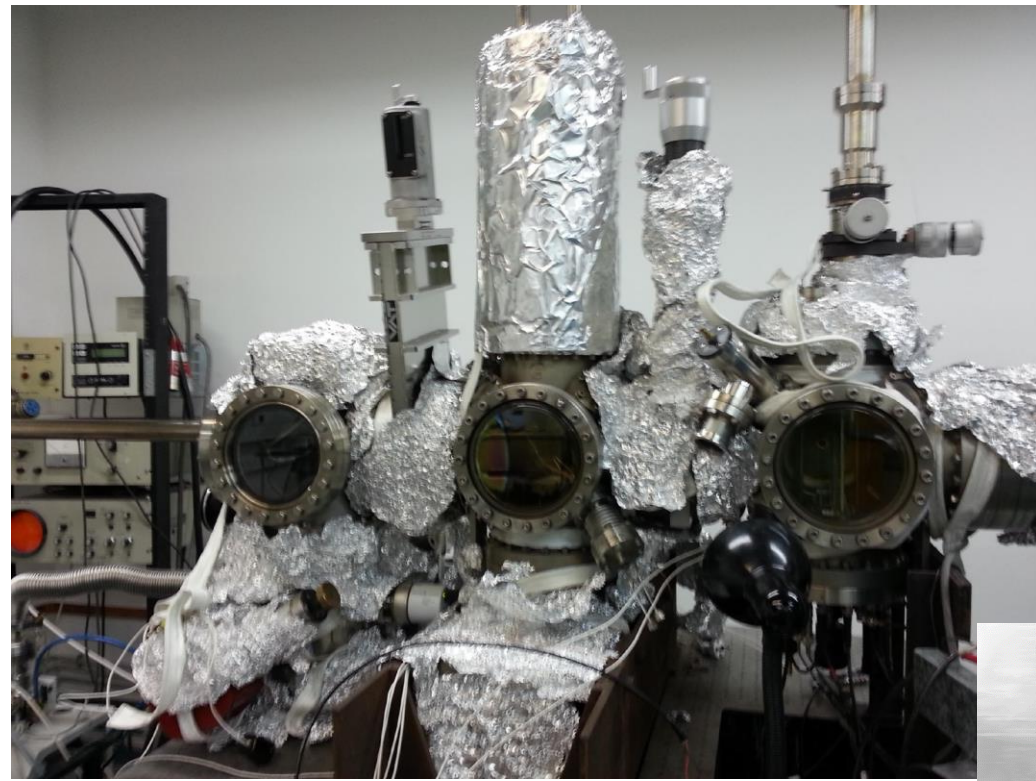
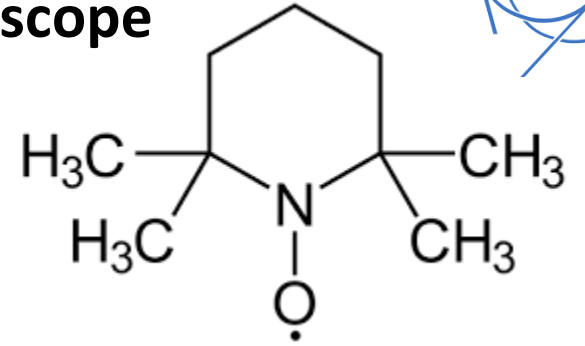


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# Electron Spin Resonance of single molecules using a scanning tunneling microscope





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# TCT

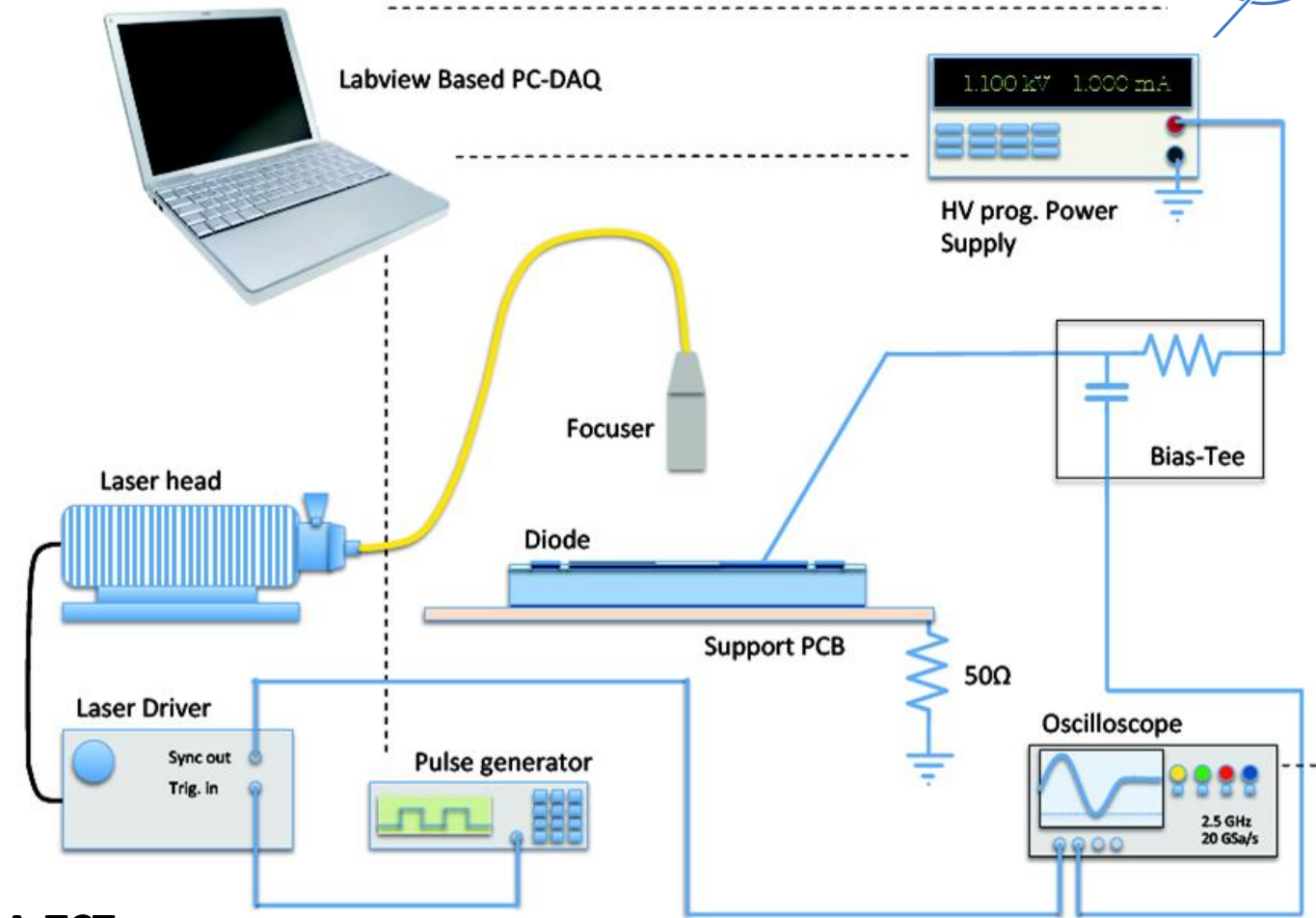
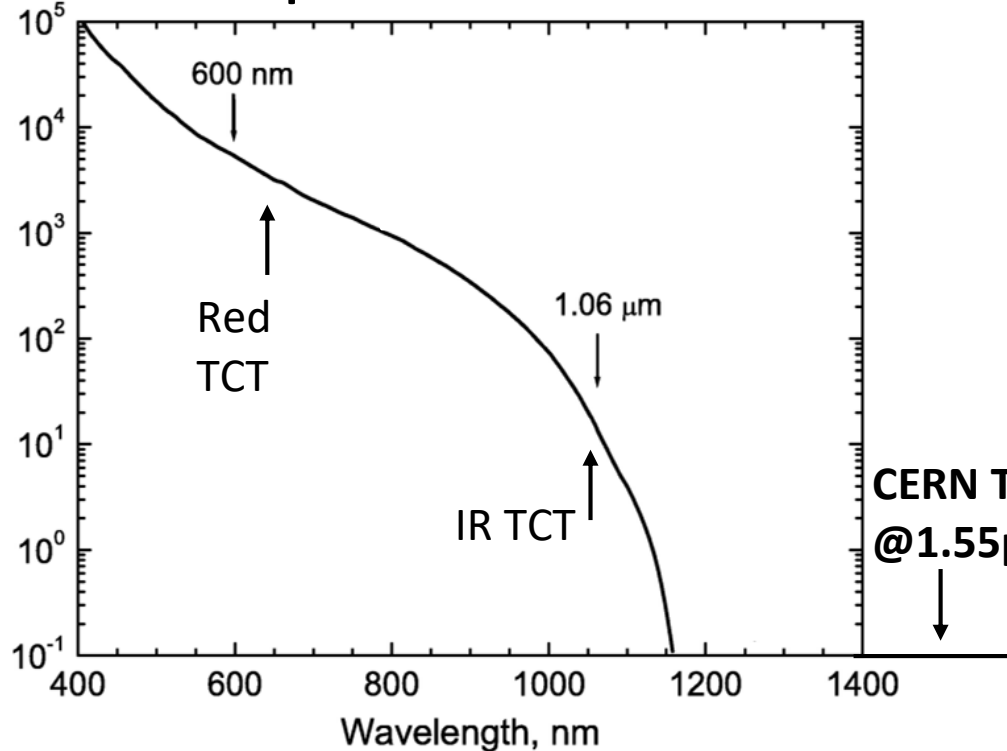


**TCT=Transient Current Technique**

Laser characterization technique: light injected in a detector -> induced current studied.

Workhorse for characterization of Si detectors within RD50 collaboration.

## Linear absorption coefficient of silicon





# Two Photon Absorption

TPA provides spatial resolution along the beam propagation direction.

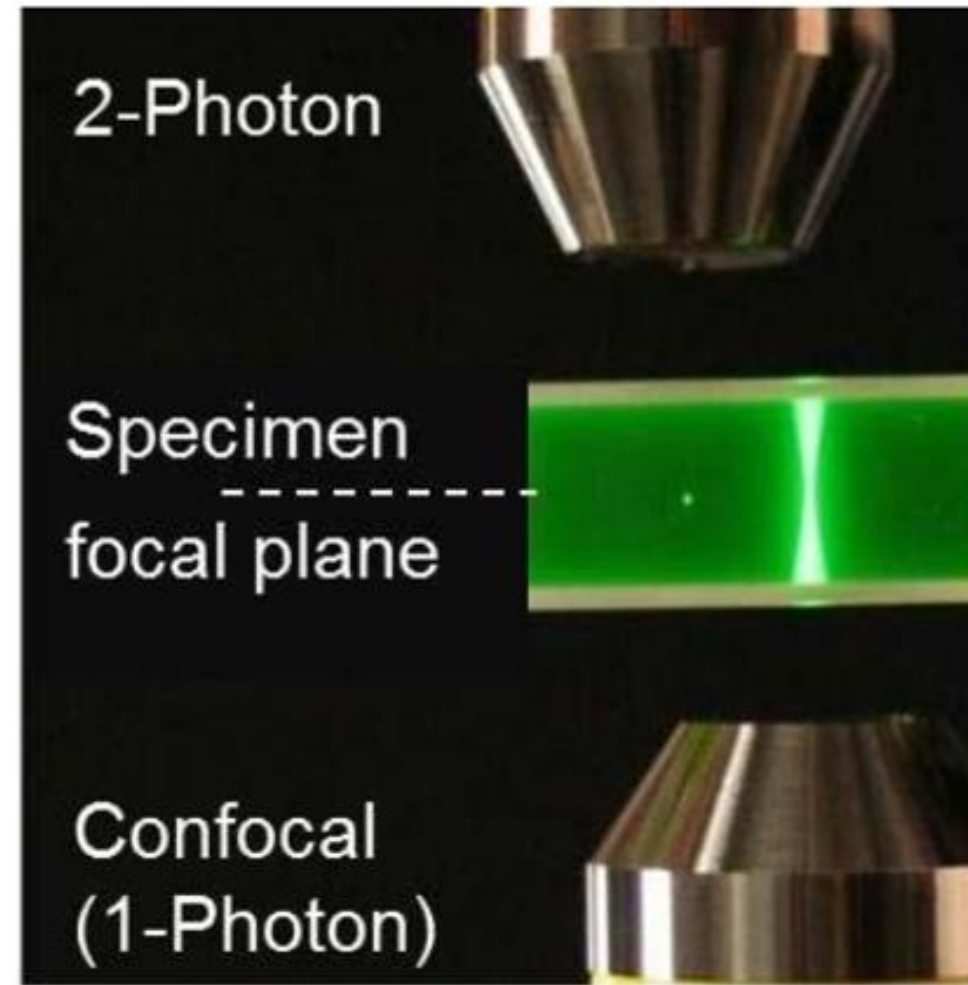
Before TPA, there was no spatial resolution along the beam propagation direction. With TPA, the laser probe is “point-like” (3D ellipsoid  $\sim 1 \times 1 \times 10 \mu\text{m}^3$ )

$$\frac{dN(r, z)}{dt} = \frac{\alpha I(r, z)}{\hbar\omega} + \frac{\beta I^2(r, z)}{2\hbar\omega}$$

Linear absorption

$N$  = density of free carriers [ $1/\text{cm}^3$ ]

$I$  = pulse irradiance [ $\text{J}/\text{cm}^2$ ]



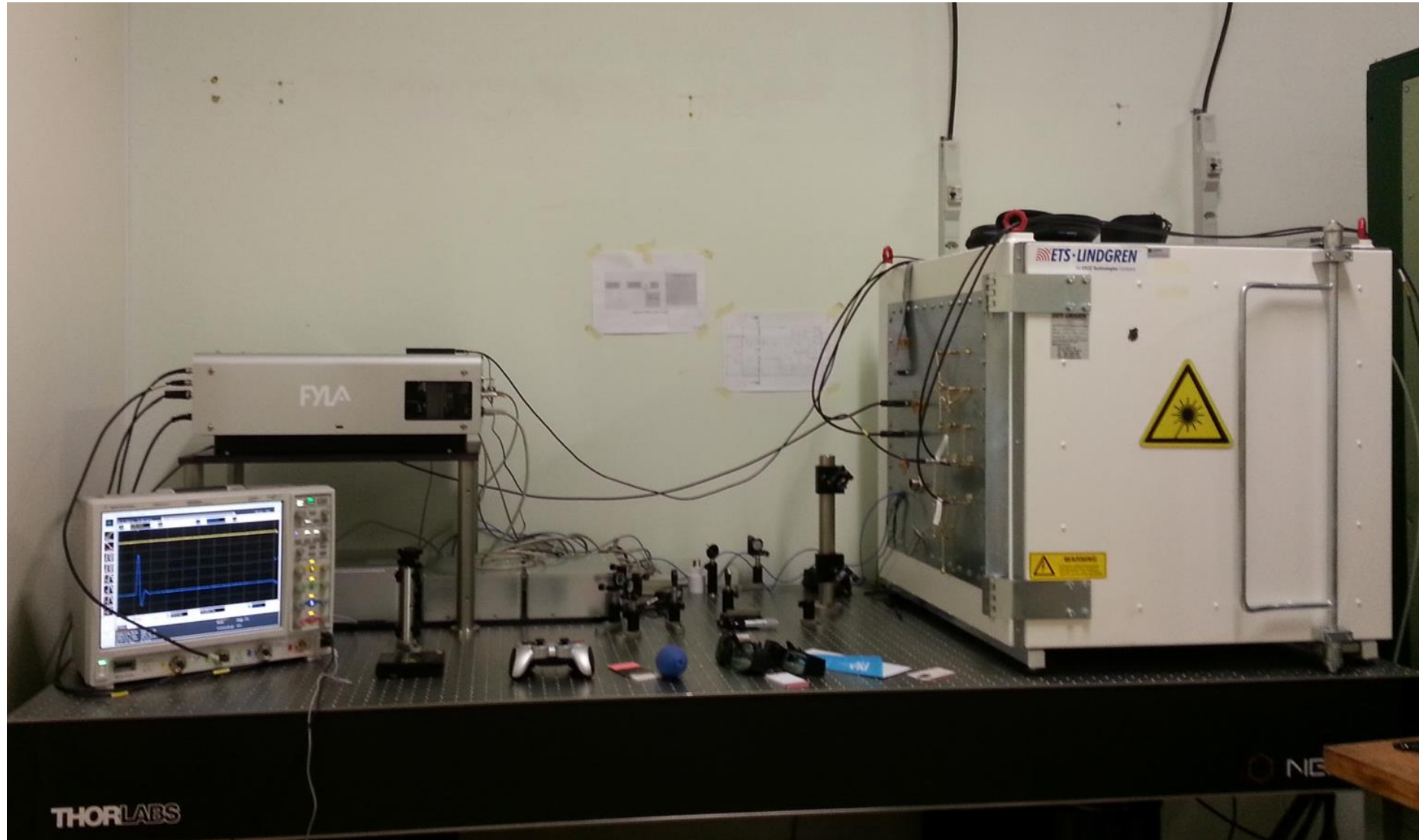
Photography: Ciceron Yanez, University of Central Florida

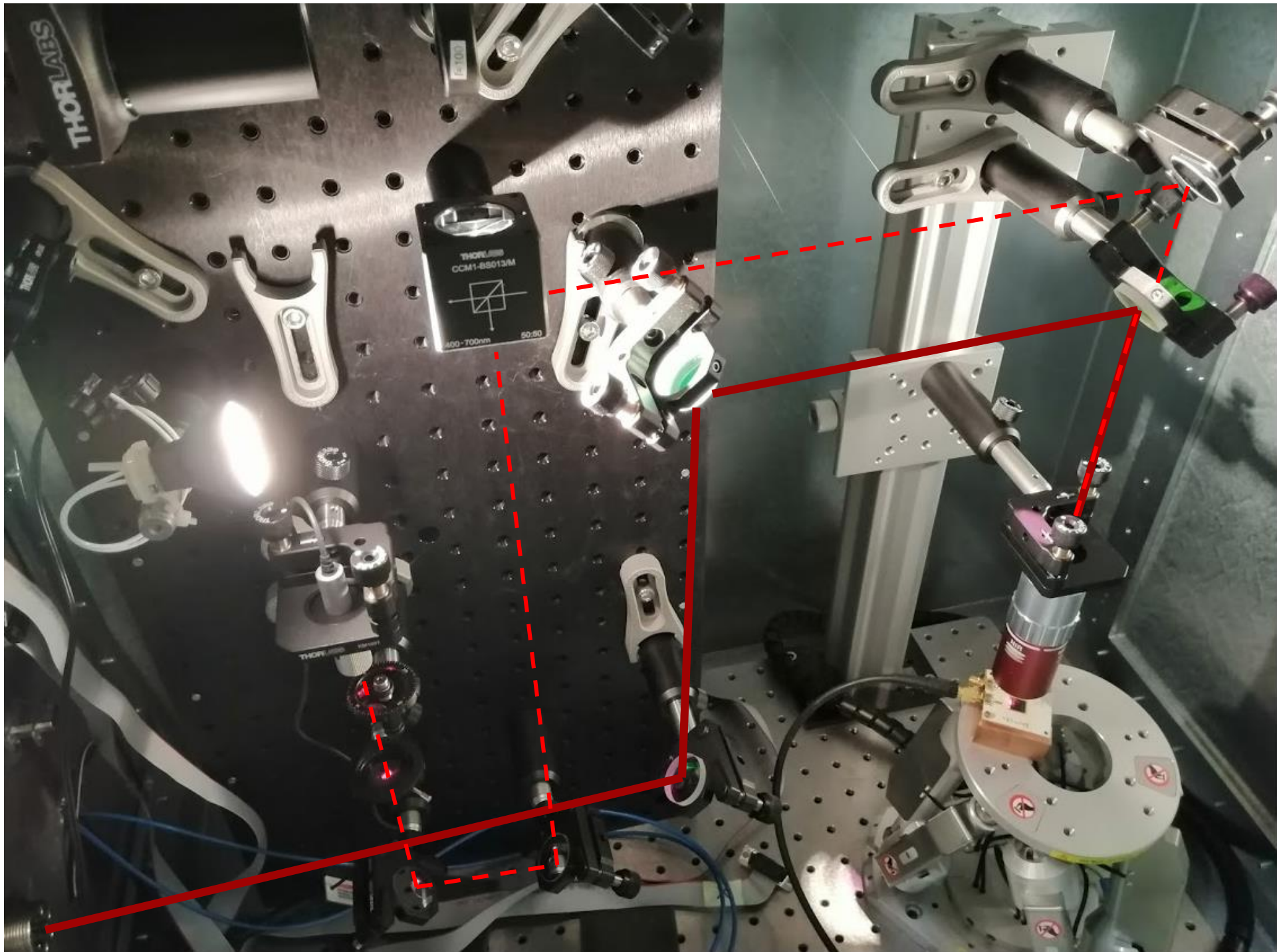
TPA-TCT uses a laser operating in Two Photon Absorption and uses TCT analysis techniques  
TPA needs high irradiance -> it happens only at the focus (x100) of the microscope objective

**Laser development funded by CERN - Knowledge Transfer program**

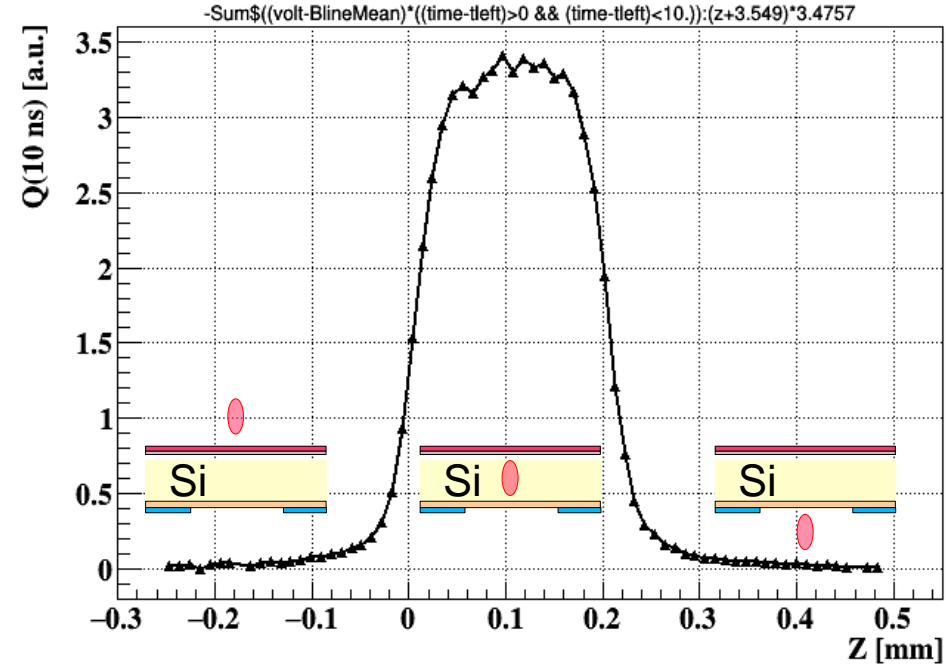
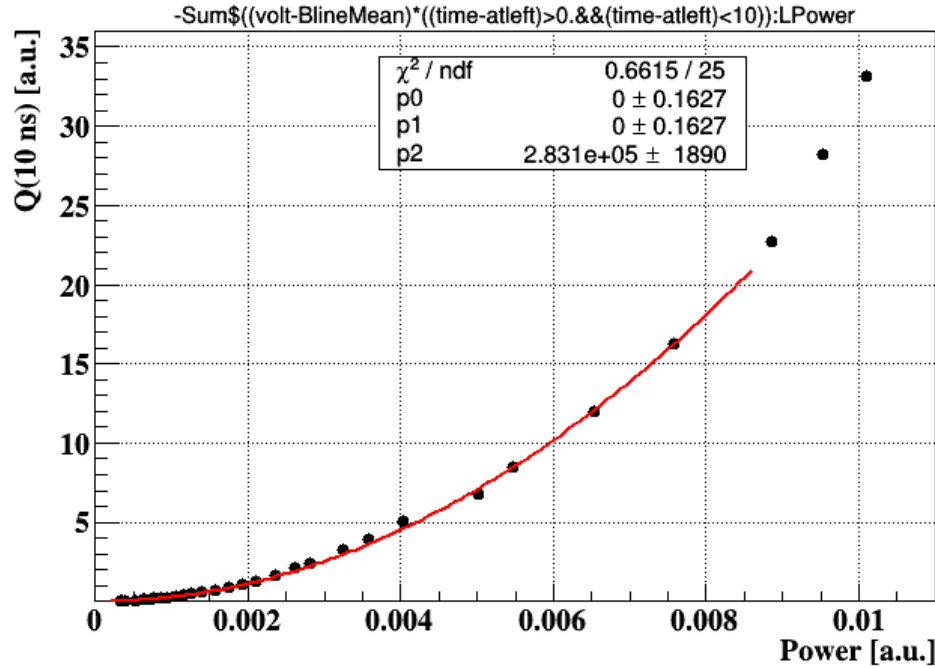
**Laser developed with the company FYLA, Spain**

**Setup assembled by Moritz Wiehe (CERN doctoral student funded by Gentner program)**





# Proof of TPA



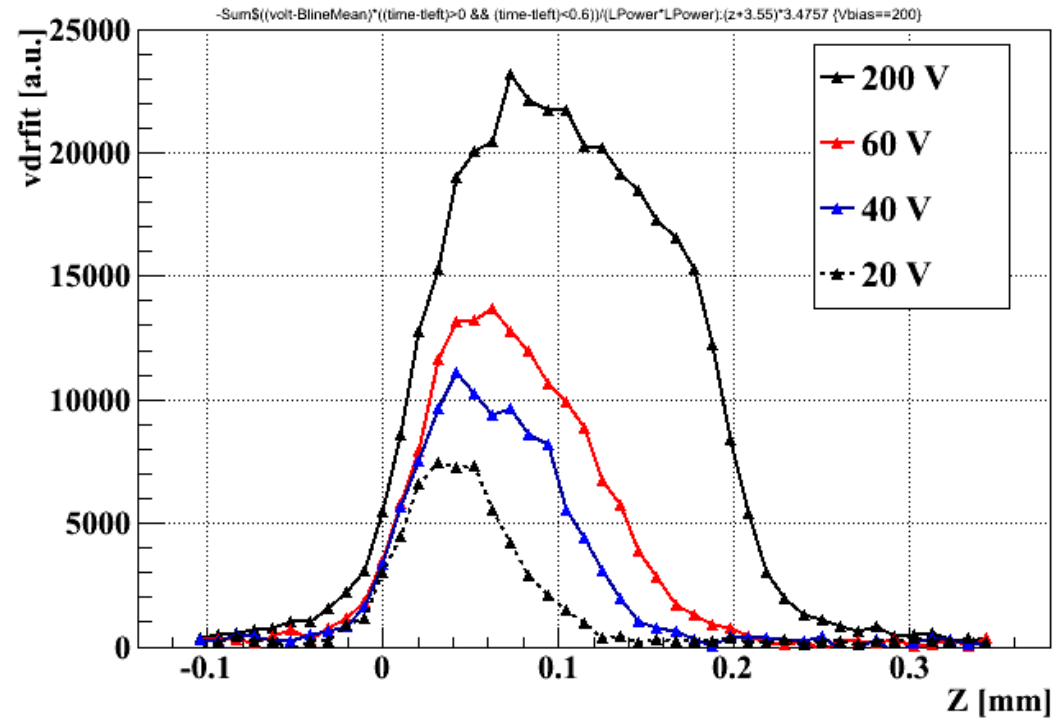
1) Quadratic relation between collected signal (in Si) and laser power

2) Carriers produced only when focus of laser is inside the detector. No signal collected outside → Spatial resolution along the beam demonstrated

$$\frac{dN(r, z)}{dt} = \frac{\beta I^2(r, z)}{2\hbar\omega} \quad \longrightarrow \quad \Delta N(r, z) = \frac{\beta I^2(r, z)}{2\hbar\omega} \Delta t$$

$Q \propto N$                        $P \propto I$

# E-field mapping in top-TPA configuration



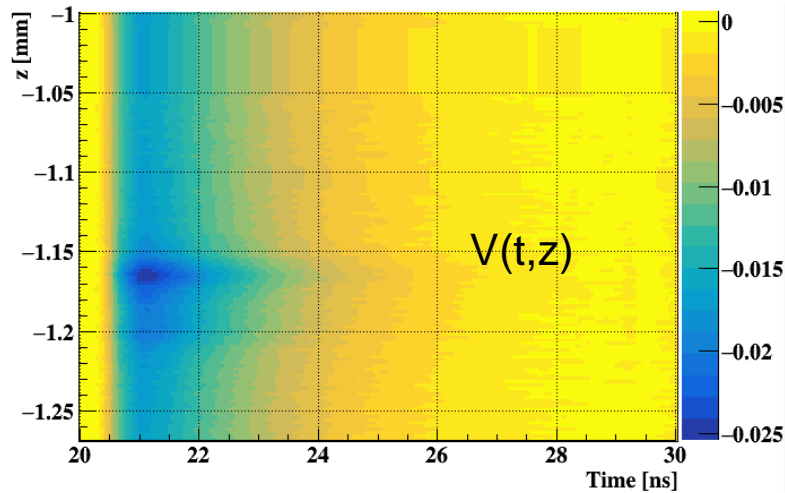
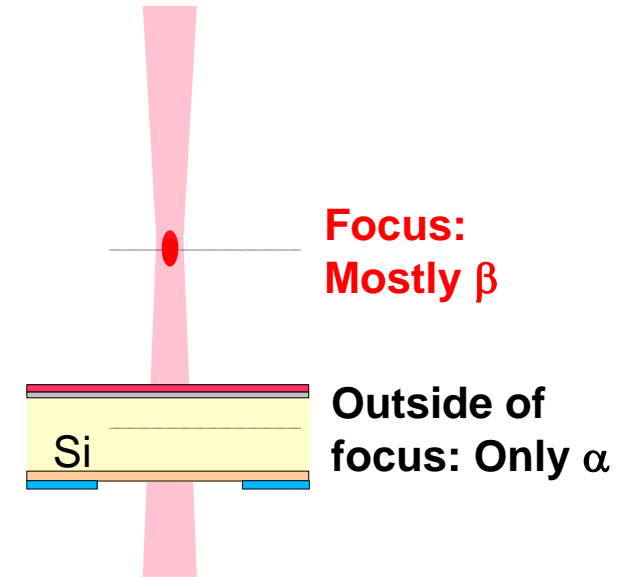
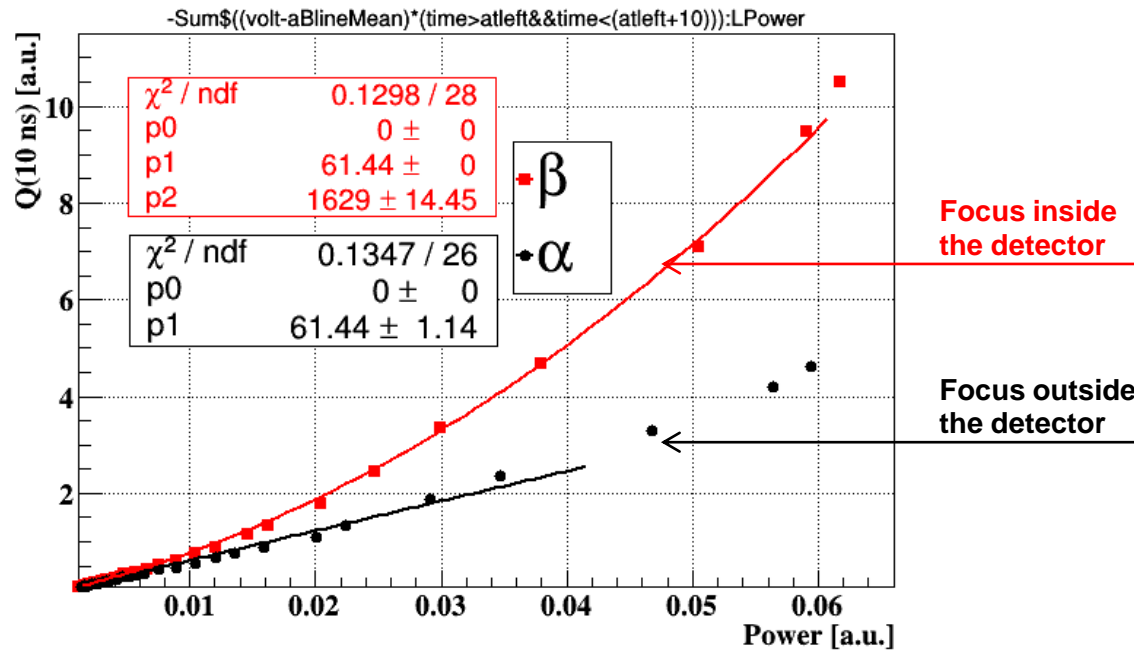
Voltage scan of HPK 200  $\mu\text{m}$  thick detector  
Shown E-field calculated as a function of depth  
Detector (not irradiated) depletes from the front  
Depletion width increases with voltage  
This measurement can not be done with top/bottom SPA-TCT

# First measurement of irradiated diodes ( $1.6 \times 10^{16} n_{eq}/cm^2$ )

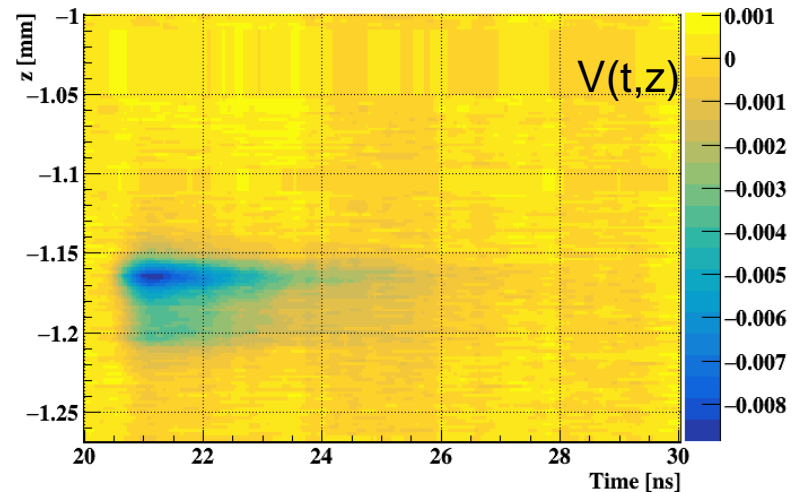


*No cooling yet*

$$\frac{dN(r,z)}{dt} = \frac{\alpha I(r,z)}{\hbar\omega} + \frac{\beta I^2(r,z)}{2\hbar\omega}$$

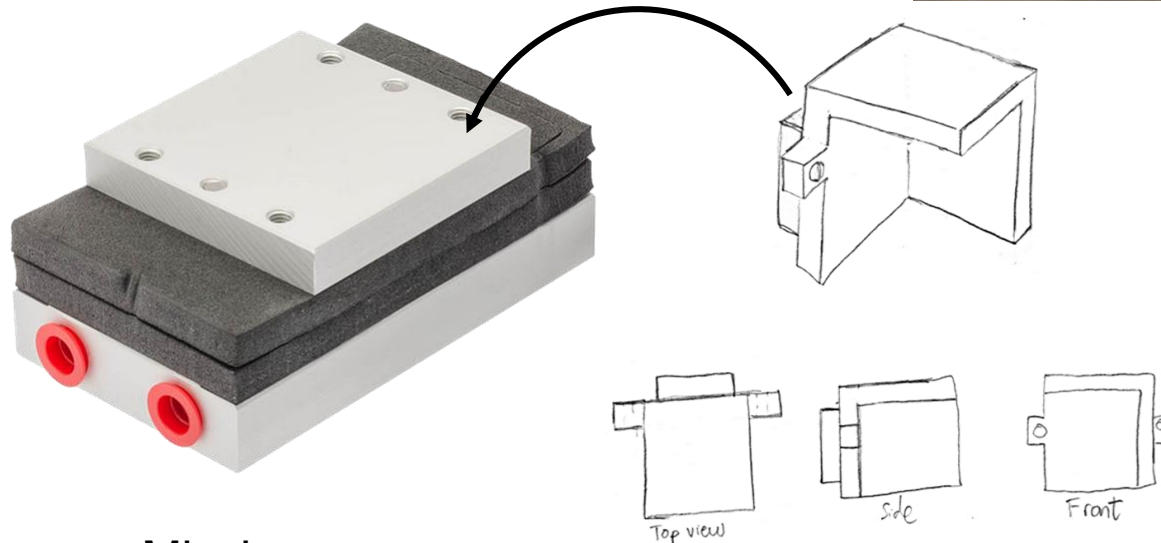
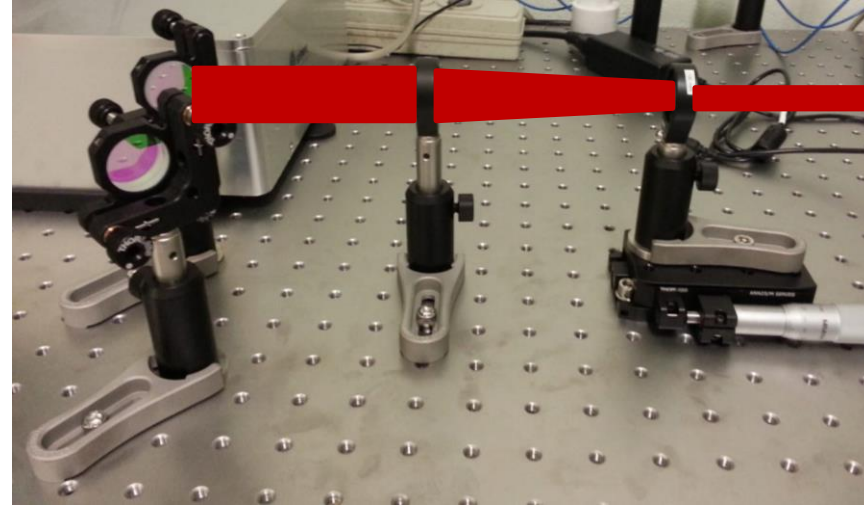


SPA corr



# Setup improvements

Addition of telescope for better coupling of the light to the microscope objective:



Creation of a cooling block sample holder compatible with edge/top injection

Missing:

- DAQ program (all measurements here were taken by hand :))
- Realization of cooling
- Edge-TPA measurements

# Conclusions

First (and only) TPA-TCT compact setup in the world being commissioned at CERN  
(another TPA setup exists in Spain, but uses a 1 room-sized laser)

- We have verified that the chosen custom parameters we ordered were correct:
  - Enough power for measurements of both irradiated and non-irradiated detectors
- We have demonstrated TPA process in a diode (top injection)
- We are able to measure irradiated detectors with good SNR
- We are still developing some parts of the system: DAQ, cooling